| PCN Number: | | 20130401003 | | | | | PCN Date: | | e: | 04/04/2013 | |
|----------------------------------|-----------------------------------|-------------|---------------------|---------------------------|-------|-------------------|-------------------------------|----------------------------|----|------------------|--|
| Title: | Title: DRV2604/DRV2605 Data Sheet | | | | | | | | | | |
| Customer Contact: | | PCN Manager | | Phon | e: | +1(214)480-6037 | | Dep | t: | Quality Services | |
| Proposed 1 st Ship Da | | te: | 07/04/2013 | | 13 | | stimated Samp vailability: | Date provided upon request | | | |
| Chan | | | | | | | | | | | |
| | Assembly Site Assembly Pr | | | oly Pro | ocess | | | Assembly Materials | | | |
| Design | | | X | Electrical Specification | | | | Mechanical Specification | | | |
| Test Site | | | F | Packing/Shipping/Labeling | | | | Test Process | | | |
| Wafer Bump Site | | | \ | Wafer Bump Material | | | | Wafer Bump Process | | | |
| Wafer Fab Site Wa | | | Wafer Fab Materials | | | Wafer Fab Process | | | | | |
| PCN Details | | | | | | | | | | | |

Description of Change:

The product datasheet(s) is being updated to Increase IIH MAX number in datasheet.

The following change history provides further details. These changes may be reviewed at the datasheet links provided.

TI INFORMATION - SELECTIVE DISCLOSURE

DRV2604



SLOS777A - DECEMBER 2012-REVISED MARCH 2013

www.ti.com

REVISION HISTORY

Changes from Original (December 2012) to Revision A

Page

Changed |I_{IH} MAX value from 3 to 3.5µA per CMS #C1303019

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TI INFORMATION - SELECTIVE DISCLOSURE

DRV2605



SLOS825A - DECEMBER 2012 - REVISED MARCH 2013

www.tl.com

From (page 4):

ELECTRICAL CHARACTERISTICS

T_A = 25°C, VDD = 3.6 V (unless otherwise noted)

| | PARAMETER | TES | T CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------|----------------------------|------|-------------------------|-----|------|-----|------|
| V _{REG} | | VREG | | | 1.84 | | V |
| H _E I | Digital input low current | EN | VDD = 5.5 V , VIN = 0 V | | | 1 | uА |
| li _H i | Digital input high current | EN | VDD = 5.5 V, VIN = VDD | | | 3 | μА |

To (page 4):

ELECTRICAL CHARACTERISTICS

T_A = 25°C, VDD = 3.6 V (unless otherwise noted)

| | PARAMETER | TES | MIN | TYP | MAX | UNIT | |
|------------------|----------------------------|------|-------------------------|-----|------|------|----|
| V _{REG} | | VREG | | | 1.84 | | V |
| H _E I | Digital input low current | EN | VDD = 5.5 V , VIN = 0 V | | | 1 | uА |
| | Digital input high current | EN | VDD = 5.5 V, VIN = VDD | | | 3.5 | μА |

Texas Instruments, Inc.

PCN# 20130401003

The datasheet number will be changing.

| Device Family | Change From: | Change To: |
|---------------|--------------|------------|
| DRV2604 | SLOS777 | SLOS777A |
| DRV2605 | SLOS825 | SLOS825A |

The updated datasheet(s) can be accessed by the following link(s):

http://www.ti.com/product/drv2604 http://www.ti.com/product/drv2605

| Reason for Change: | | | | | | | |
|--|--|--|--|--|--|--|--|
| To more accurately reflect device characteristics. | | | | | | | |
| Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): | | | | | | | |
| Electrical specification performance changes as indicated above. | | | | | | | |
| Changes to product identification resulting from this PCN: | | | | | | | |
| None | | | | | | | |
| Product Affected: | | | | | | | |
| DRV2604YZFR DRV2604YZFT DRV2605YZFR DRV2605YZFT | | | | | | | |

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

| Location | E-Mail |
|--------------|--------------------------------|
| USA | PCNAmericasContact@list.ti.com |
| Europe | PCNEuropeContact@list.ti.com |
| Asia Pacific | PCNAsiaContact@list.ti.com |
| Japan | PCNJapanContact@list.ti.com |